NSN 5961-01-074-7567

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-074-7567 **Inclosure Material:** Ceramic **Overall Length:** 1.000 inches **End Application:** Power conditioning system, fa-10062 (pcs) **Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 off-state voltage, rms total **Current Rating Per Characteristic:** 1000.00 amperes drain current nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 case and 2 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0